## Toupler Digital Isolater

## FEATURES

High data rate: dc to $\mathbf{1 0 0}$ Mbps (NRZ)
Compatible with 3.3 V and 5.0 V operation/level translation
$125^{\circ} \mathrm{C}$ maximum operating temperature
Low power operation
5 V operation
1.0 mA maximum @ 1 Mbps
4.5 mA maximum @ 25 Mbps
16.8 mA maximum @ 100 Mbps
3.3 V operation
0.4 mA maximum @ 1 Mbps
3.5 mA maximum @ 25 Mbps
7.1 mA maximum @ 50 Mbps

8-lead SOIC_N package (RoHS compliant version available)
High common-mode transient immunity: > $\mathbf{2 5} \mathbf{~ k V} / \mu \mathrm{s}$
Safety and regulatory information
UL recognized
2500 V rms for 1 minute per UL 1577
CSA Component Acceptance Notice \#5A
VDE Certificate of Conformity
DIN V VDE V 0884-10 (VDE V 0884-10):2006-12
VIORM $=560$ V peak

## APPLICATIONS

Digital field bus isolation
Opto-isolator replacement
Computer-peripheral interface
Microprocessor system interface
General instrumentation and data acquisition applications

## GENERAL DESCRIPTION

The ADuM1100 ${ }^{1}$ is a digital isolator based on Analog Devices Inc. $i$ Coupler ${ }^{\ominus}$ technology. Combining high speed CMOS and monolithic air core transformer technology, this isolation component provides outstanding performance characteristics superior to alternatives, such as optocoupler devices.

Configured as a pin-compatible replacement for existing high speed optocouplers, the ADuM1100 supports data rates as high as 25 Mbps and 100 Mbps .
The ADuM1 100 operates with a voltage supply ranging from 3.0 V to 5.5 V , boasts a propagation delay of $<18 \mathrm{~ns}$ and edge asymmetry of $<2 \mathrm{~ns}$, and is compatible with temperatures up to $125^{\circ} \mathrm{C}$. It operates at very low power, less than 0.9 mA of quiescent current (sum of both sides), and a dynamic current of less than $160 \mu \mathrm{~A}$ per Mbps of data rate. Unlike other optocoupler alternatives, the ADuM1100 provides dc correctness with a patented refresh feature that continuously updates the output signal.
The ADuM1100 is offered in three grades. The ADuM1100AR and ADuM1100BR can operate up to a maximum temperature of $105^{\circ} \mathrm{C}$ and support data rates up to 25 Mbps and 100 Mbps , respectively. The ADuM1100UR can operate up to a maximum temperature of $125^{\circ} \mathrm{C}$ and supports data rates up to 100 Mbps .

[^0]

Figure 1.

Rev. G

## ADuM1100

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## SPECIFICATIONS

## ELECTRICAL SPECIFICATIONS-5 V OPERATION

All voltages are relative to their respective ground. $4.5 \mathrm{~V} \leq \mathrm{V}_{\mathrm{DD} 1} \leq 5.5 \mathrm{~V}, 4.5 \mathrm{~V} \leq \mathrm{V}_{\mathrm{DD} 2} \leq 5.5 \mathrm{~V}$. All minimum/maximum specifications apply over the entire recommended operation range, unless otherwise noted. All typical specifications are at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{DD} 1}=\mathrm{V}_{\mathrm{DD} 2}=5 \mathrm{~V}$.

Table 1.

| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| DC SPECIFICATIONS |  |  |  |  |  |  |
| Input Supply Current | $\mathrm{IDD1}$ (0) |  | 0.3 | 0.8 | mA | $\mathrm{V}_{1}=0 \mathrm{~V}$ or $\mathrm{V}_{\mathrm{DD} 1}$ |
| Output Supply Current | IDD2 (0) |  | 0.01 | 0.06 | mA | $\mathrm{V}_{1}=0 \mathrm{~V}$ or $\mathrm{V}_{\mathrm{DD} 1}$ |
| Input Supply Current ( 25 Mbps ) (See Figure 5) | IDD1 (25) |  | 2.2 | 3.5 | mA | 12.5 MHz logic signal frequency |
| Output Supply Current ${ }^{1}$ ( 25 Mbps ) (See Figure 6) | IDD2 (25) |  | 0.5 | 1.0 | mA | 12.5 MHz logic signal frequency |
| Input Supply Current (100 Mbps) (See Figure 5) | $\mathrm{IDD1}(100)$ |  | 9.0 | 14 | mA | 50 MHz logic signal frequency, ADuM1100BR/ADuM1100UR only |
| Output Supply Current ${ }^{1}$ (100 Mbps) (See Figure 6) | IDD2 (100) |  | 2.0 | 2.8 | mA | 50 MHz logic signal frequency, ADuM1100BR/ADuM1100UR only |
| Input Current | 1 | -10 | +0.01 | +10 | $\mu \mathrm{A}$ | $0 \mathrm{~V} \leq \mathrm{V}_{\text {IN }} \leq \mathrm{V}_{\mathrm{DD} 1}$ |
| Logic High Output Voltage | V OH | $V_{\text {DD2 }}-0.1$ | 5.0 |  | V | $\mathrm{l}_{0}=-20 \mu \mathrm{~A}, \mathrm{~V}_{1}=\mathrm{V}_{\mathrm{IH}}$ |
|  |  | $V_{D D 2}-0.8$ | 4.6 |  | V | $\mathrm{l}_{\mathrm{o}}=-4 \mathrm{~mA}, \mathrm{~V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{H}}$ |
| Logic Low Output Voltage | Vol |  | 0.0 | 0.1 | V | $\mathrm{l}_{\mathrm{O}}=20 \mu \mathrm{~A}, \mathrm{~V}_{\mathrm{l}}=\mathrm{V}_{\mathrm{IL}}$ |
|  |  |  | 0.03 | 0.1 | V | $\mathrm{lo}=400 \mu \mathrm{~A}, \mathrm{~V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{IL}}$ |
|  |  |  | 0.3 | 0.8 | V | $\mathrm{l}_{\mathrm{l}}=4 \mathrm{~mA}, \mathrm{~V}_{\mathrm{l}}=\mathrm{V}_{\text {IL }}$ |
| SWITCHING SPECIFICATIONS |  |  |  |  |  |  |
| For ADuM1100AR |  |  |  |  |  |  |
| Minimum Pulse Width ${ }^{2}$ | PW |  |  | 40 | ns | $C_{L}=15 \mathrm{pF}$, CMOS signal levels |
| Maximum Data Rate ${ }^{3}$ |  | 25 |  |  | Mbps | $C_{L}=15 \mathrm{pF}$, CMOS signal levels |
| For ADuM1100BR/ADuM1100UR |  |  |  |  |  |  |
| Minimum Pulse Width ${ }^{2}$ | PW |  | 6.7 | 10 | ns | $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}, \mathrm{CMOS}$ signal levels |
| Maximum Data Rate ${ }^{3}$ |  | 100 | 150 |  | Mbps | $C_{L}=15 \mathrm{pF}, \mathrm{CMOS}$ signal levels |
| For All Grades |  |  |  |  |  |  |
| Propagation Delay Time to Logic Low Output ${ }^{4,5}$ (See Figure 7) | $\mathrm{t}_{\text {PHL }}$ |  | 10.5 | 18 | ns | $C_{L}=15 \mathrm{pF}, \mathrm{CMOS}$ signal levels |
| Propagation Delay Time to Logic High Output ${ }^{4,5}$ (See Figure 7) | tpLH |  | 10.5 | 18 | ns | $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}, \mathrm{CMOS}$ signal levels |
| Pulse Width Distortion $\left\|t_{\text {tLH }}-\mathrm{t}_{\text {PHL }}\right\|^{5}$ | PWD |  | 0.5 | 2 | ns | $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}, \mathrm{CMOS}$ signal levels |
| Change vs. Temperature ${ }^{6}$ |  |  | 3 |  | ps $/{ }^{\circ} \mathrm{C}$ | $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}, \mathrm{CMOS}$ signal levels |
| Propagation Delay Skew (Equal Temperature) ${ }^{5,7}$ | tpsk1 |  |  | 8 | ns | $C_{L}=15 \mathrm{pF}, \mathrm{CMOS}$ signal levels |
| Propagation Delay Skew (Equal Temperature, Supplies) ${ }^{5,7}$ | tpsk2 |  |  | 6 | ns | $C_{L}=15 \mathrm{pF}, \mathrm{CMOS}$ signal levels |
| Output Rise/Fall Time | $\mathrm{t}_{\mathrm{R},} \mathrm{t}_{\mathrm{F}}$ |  | 3 |  | ns | $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}, \mathrm{CMOS}$ signal levels |
| Common-Mode Transient Immunity at Logic Low/High Output ${ }^{8}$ | $\begin{aligned} & \left\|\mathrm{CM}_{\llcorner }\right\|, \\ & \left\|\mathrm{CM}_{\mathrm{H}}\right\| \end{aligned}$ | 25 | 35 |  | kV/ $\mu \mathrm{s}$ | $\mathrm{V}_{1}=0 \mathrm{~V}$ or $\mathrm{V}_{\mathrm{DD}}, \mathrm{V}_{\mathrm{CM}}=1000 \mathrm{~V}$, transien transient magnitude $=800 \mathrm{~V}$ |
| Refresh Rate | $\mathrm{fr}_{\mathrm{r}}$ |  | 1.2 |  | Mbps |  |
| Input Dynamic Supply Current ${ }^{9}$ | lodi (D) |  | 0.09 |  | mA/Mbps |  |
| Output Dynamic Supply Current ${ }^{9}$ | IDDO (D) |  | 0.02 |  | mA/Mbps |  |

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${ }^{1}$ Output supply current values are with no output load present. See Figure 5 and Figure 6 for information on supply current variation with logic signal frequency. See the Power Consumption section for guidance on calculating the input and output supply currents for a given data rate and output load.
${ }^{2}$ The minimum pulse width is the shortest pulse width at which the specified pulse width distortion is guaranteed.
${ }^{3}$ The maximum data rate is the fastest data rate at which the specified pulse width distortion is guaranteed.
${ }^{4} t_{\text {PHL }}$ is measured from the $50 \%$ level of the falling edge of the $V_{I}$ signal to the $50 \%$ level of the falling edge of the $V_{0}$ signal. $t_{\text {PLH }}$ is measured from the $50 \%$ level of the rising edge of the $\mathrm{V}_{1}$ signal to the $50 \%$ level of the rising edge of the $\mathrm{V}_{0}$ signal.
${ }^{5}$ Because the input thresholds of the ADuM1100 are at voltages other than the $50 \%$ level of typical input signals, the measured propagation delay and pulse width distortion can be affected by slow input rise/fall times. See the Propagation Delay-Related Parameters section and Figure 14 through Figure 18 for information on the impact of given input rise/fall times on these parameters.
${ }^{6}$ Pulse width distortion change vs. temperature is the absolute value of the change in pulse width distortion for a $1^{\circ} \mathrm{C}$ change in operating temperature.
${ }^{7}$ tpsk $^{\prime}$ is the magnitude of the worst-case difference in $t_{\text {PHL }}$ and/or $t_{\text {PLH }}$ that is measured between units at the same operating temperature and output load within the recommended operating conditions. $\mathrm{t}_{\text {PK } 2}$ is the magnitude of the worst-case difference in $^{t_{\text {PHL }}}$ and/or $t_{\text {PLH }}$ that is measured between units at the same operating temperature, supply voltages, and output load within the recommended operating conditions.
${ }^{8} \mathrm{CM}_{\mathrm{H}}$ is the maximum common-mode voltage slew rate that can be sustained while maintaining $\mathrm{V}_{\mathrm{O}}>0.8 \mathrm{~V}_{\mathrm{DD} 2}$. $\mathrm{CM}_{\mathrm{L}}$ is the maximum common-mode voltage slew rate that can be sustained while maintaining $\mathrm{V}_{0}<0.8 \mathrm{~V}$. The common-mode voltage slew rates apply to both rising and falling edges. The transient magnitude is the range over which the common-mode is slewed.
${ }^{9}$ Dynamic supply current is the incremental amount of supply current required for a 1 Mbps increase in signal data rate. See Figure 5 and Figure 6 for information on supply current variation with logic signal frequency. See the Power Consumption section for guidance on calculating the input and output supply currents for a given data rate and output load.

## ELECTRICAL SPECIFICATIONS—3.3 V OPERATION

All voltages are relative to their respective ground. $3.0 \mathrm{~V} \leq \mathrm{V}_{\mathrm{DD} 1} \leq 3.6 \mathrm{~V}, 3.0 \mathrm{~V} \leq \mathrm{V}_{\mathrm{DD} 2} \leq 3.6 \mathrm{~V}$. All minimum/maximum specifications apply over the entire recommended operation range, unless otherwise noted. All typical specifications are at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{DD} 1}=\mathrm{V}_{\mathrm{DD} 2}=3.3 \mathrm{~V}$.

Table 2.

| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| DC SPECIFICATIONS |  |  |  |  |  |  |
| Input Supply Current | $\mathrm{ldD1}$ (0) |  | 0.1 | 0.3 | mA | $\mathrm{V}_{1}=0 \mathrm{~V}$ or $\mathrm{V}_{\text {DD } 1}$ |
| Output Supply Current | l DD2 (0) |  | 0.005 | 0.04 | mA | $\mathrm{V}_{1}=0 \mathrm{~V}$ or $\mathrm{V}_{\text {DD } 1}$ |
| Input Supply Current ( 25 Mbps ) (See Figure 5) | ldD1 (25) |  | 2.0 | 2.8 | mA | 12.5 MHz logic signal frequency |
| Output Supply Current ${ }^{1}$ ( 25 Mbps ) (See Figure 6) | IDD2 (25) |  | 0.3 | 0.7 | mA | 12.5 MHz logic signal frequency |
| Input Supply Current ( 50 Mbps ) (See Figure 5) | IDD1 (50) |  | 4.0 | 6.0 | mA | 25 MHz logic signal frequency, ADuM1100BR/ADuM1100UR only |
| Output Supply Current ${ }^{1}$ ( 50 Mbps ) (See Figure 6) | $\mathrm{I}_{\text {DD2 (50) }}$ |  | 1.2 | 1.6 | mA | 25 MHz logic signal frequency, ADuM1100BR/ADuM1100UR only |
| Input Current | 1 | -10 | +0.01 | +10 | $\mu \mathrm{A}$ | $0 \mathrm{~V} \leq \mathrm{V}_{\text {IN }} \leq \mathrm{V}_{\mathrm{DD} 1}$ |
| Logic High Output Voltage | V OH | $V_{\text {DD2 } 2}-0.1$ | 3.3 |  | V | $\mathrm{l}_{0}=-20 \mu \mathrm{~A}, \mathrm{~V}_{1}=\mathrm{V}_{\mathrm{IH}}$ |
|  |  | $V_{\text {DD2 } 2}-0.5$ | 3.0 |  | V | $\mathrm{l}_{0}=-2.5 \mathrm{~mA}, \mathrm{~V}_{\mathrm{I}}=\mathrm{V}_{1 H}$ |
| Logic Low Output Voltage | Voı |  | 0.0 | 0.1 | V | $\mathrm{lo}=20 \mu \mathrm{~A}, \mathrm{~V}_{\mathrm{l}}=\mathrm{V}_{\mathrm{H}}$ |
|  |  |  | 0.04 | 0.1 | V | $\mathrm{l}_{0}=400 \mu \mathrm{~A}, \mathrm{~V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{IH}}$ |
|  |  |  | 0.3 | 0.4 | V | $\mathrm{l}_{0}=2.5 \mathrm{~mA}, \mathrm{~V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{IH}}$ |
| SWITCHING SPECIFICATIONS |  |  |  |  |  |  |
| For ADuM1100AR |  |  |  |  |  |  |
| Minimum Pulse Width ${ }^{2}$ | PW |  |  | 40 | ns | $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$, CMOS signal levels |
| Maximum Data Rate ${ }^{3}$ |  | 25 |  |  | Mbps | $C_{L}=15 \mathrm{pF}, \mathrm{CMOS}$ signal levels |
| For ADuM1100BR/ADuM1100UR |  |  |  |  |  |  |
| Minimum Pulse Width ${ }^{2}$ | PW |  | 10 | 20 | ns | $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$, CMOS signal levels |
| Maximum Data Rate ${ }^{3}$ |  | 50 | 100 |  | Mbps | $C_{L}=15 \mathrm{pF}, \mathrm{CMOS}$ signal levels |
| For All Grades |  |  |  |  |  |  |
| Propagation Delay Time to Logic Low Output ${ }^{4,5}$ (See Figure 8) | $\mathrm{t}_{\text {PHL }}$ |  | 14.5 | 28 | ns | $C_{L}=15 \mathrm{pF}, \mathrm{CMOS}$ signal levels |
| Propagation Delay Time to Logic High Output ${ }^{4,5}$ (See Figure 8) | tpLh $^{\text {l }}$ |  | 15.0 | 28 | ns | $C_{L}=15 \mathrm{pF}, \mathrm{CMOS}$ signal levels |
| Pulse Width Distortion $\left\|t_{\text {PLH }}-\mathrm{t}_{\text {PHL }}\right\|^{5}$ | PWD |  | 0.5 | 3 | ns | $C_{L}=15 \mathrm{pF}, \mathrm{CMOS}$ signal levels |
| Change vs. Temperature ${ }^{6}$ |  |  | 10 |  | $\mathrm{ps} /{ }^{\circ} \mathrm{C}$ | $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}, \mathrm{CMOS}$ signal levels |
| Propagation Delay Skew (Equal Temperature) ${ }^{5,7}$ | $\mathrm{t}_{\text {PSK1 }}$ |  |  | 15 | ns | $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}, \mathrm{CMOS}$ signal levels |
| Propagation Delay Skew (Equal Temperature, Supplies) ${ }^{5,7}$ | $\mathrm{t}_{\text {PSK2 }}$ |  |  | 12 | ns | $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}, \mathrm{CMOS}$ signal levels |
| Output Rise/Fall Time | $\mathrm{t}_{\mathrm{R},} \mathrm{t}_{\mathrm{F}}$ |  | 3 |  | ns | $C_{L}=15 \mathrm{pF}, \mathrm{CMOS}$ signal levels |
| Common-Mode Transient Immunity at Logic Low/High Output ${ }^{8}$ | $\begin{aligned} & \left\|\mathrm{CM}_{\mathrm{L}}\right\|, \\ & \left\|\mathrm{CM}_{\mathrm{H}}\right\| \end{aligned}$ | 25 | 35 |  | kV/ $\mu \mathrm{s}$ | $\begin{aligned} & \mathrm{V}_{1}=0 \mathrm{~V} \text { or } \mathrm{V}_{\mathrm{DD} 1}, \mathrm{~V}_{\mathrm{CM}}=1000 \mathrm{~V}, \\ & \text { transient magnitude }=800 \mathrm{~V} \end{aligned}$ |
| Refresh Rate | $\mathrm{fr}_{\mathrm{r}}$ |  | 1.1 |  | Mbps |  |
| Input Dynamic Supply Current ${ }^{9}$ | lodi( $)^{\text {l }}$ |  | 0.08 |  | mA/Mbps |  |
| Output Dynamic Supply Current ${ }^{9}$ | IDDO (D) |  | 0.04 |  | mA/Mbps |  |

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${ }^{1}$ Output supply current values are with no output load present. See Figure 5 and Figure 6 for information on supply current variation with logic signal frequency. See the Power Consumption section for guidance on calculating the input and output supply currents for a given data rate and output load.
${ }^{2}$ The minimum pulse width is the shortest pulse width at which the specified pulse width distortion is guaranteed.
${ }^{3}$ The maximum data rate is the fastest data rate at which the specified pulse width distortion is guaranteed.
${ }^{4} t_{\text {PHL }}$ is measured from the $50 \%$ level of the falling edge of the $V_{I}$ signal to the $50 \%$ level of the falling edge of the $V_{0}$ signal. $t_{\text {PLH }}$ is measured from the $50 \%$ level of the rising edge of the $\mathrm{V}_{1}$ signal to the $50 \%$ level of the rising edge of the $\mathrm{V}_{0}$ signal.
${ }^{5}$ Because the input thresholds of the ADuM1100 are at voltages other than the $50 \%$ level of typical input signals, the measured propagation delay and pulse width distortion can be affected by slow input rise/fall times. See the Propagation Delay-Related Parameters section and Figure 14 through Figure 18 for information on the impact of given input rise/fall times on these parameters.
${ }^{6}$ Pulse width distortion change vs. temperature is the absolute value of the change in pulse width distortion for a $1^{\circ} \mathrm{C}$ change in operating temperature.
${ }^{7}$ tpsk $^{\prime}$ is the magnitude of the worst-case difference in $t_{\text {PHL }}$ and/or $t_{\text {PLH }}$ that is measured between units at the same operating temperature and output load within the recommended operating conditions. $\mathrm{t}_{\text {PK } 2}$ is the magnitude of the worst-case difference in $^{t_{\text {PHL }}}$ and/or $t_{\text {PLH }}$ that is measured between units at the same operating temperature, supply voltages, and output load within the recommended operating conditions.
${ }^{8} \mathrm{CM}_{\mathrm{H}}$ is the maximum common-mode voltage slew rate that can be sustained while maintaining $\mathrm{V}_{\mathrm{O}}>0.8 \mathrm{~V}_{\mathrm{DD} 2}$. $\mathrm{CM}_{\mathrm{L}}$ is the maximum common-mode voltage slew rate that can be sustained while maintaining $\mathrm{V}_{0}<0.8 \mathrm{~V}$. The common-mode voltage slew rates apply to both rising and falling edges. The transient magnitude is the range over which the common-mode is slewed.
${ }^{9}$ Dynamic supply current is the incremental amount of supply current required for a 1 Mbps increase in signal data rate. See Figure 5 and Figure 6 for information on supply current variation with logic signal frequency. See the Power Consumption section for guidance on calculating the input and output supply currents for a given data rate and output load.

## ELECTRICAL SPECIFICATIONS—MIXED 5 V/3 V OR 3 V/5 V OPERATION

All voltages are relative to their respective ground. $5 \mathrm{~V} / 3 \mathrm{~V}$ operation: $4.5 \mathrm{~V} \leq \mathrm{V}_{\mathrm{DD} 1} \leq 5.5 \mathrm{~V}, 3.0 \mathrm{~V} \leq \mathrm{V}_{\mathrm{DD} 2} \leq 3.6 \mathrm{~V} .3 \mathrm{~V} / 5 \mathrm{~V}$ operation: 3.0 V $\leq \mathrm{V}_{\mathrm{DD} 1} \leq 3.6 \mathrm{~V}, 4.5 \mathrm{~V} \leq \mathrm{V}_{\mathrm{DD} 2} \leq 5.5 \mathrm{~V}$. All minimum/maximum specifications apply over the entire recommended operation range, unless otherwise noted. All typical specifications are at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{DD} 1}=3.3 \mathrm{~V}, \mathrm{~V}_{\mathrm{DD} 2}=5 \mathrm{~V}$ or $\mathrm{V}_{\mathrm{DD} 1}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{DD} 2}=3.3 \mathrm{~V}$.

Table 3.

| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| DC SPECIFICATIONS |  |  |  |  |  |  |
| Input Supply Current, Quiescent | IDDI(0) |  |  |  |  |  |
| $5 \mathrm{~V} / 3 \mathrm{~V}$ Operation |  |  | 0.3 | 0.8 | mA |  |
| $3 \mathrm{~V} / 5 \mathrm{~V}$ Operation |  |  | 0.1 | 0.3 | mA |  |
| Output Supply Current, Quiescent | IDDo (0) |  |  |  |  |  |
| $5 \mathrm{~V} / 3 \mathrm{~V}$ Operation |  |  | 0.005 | 0.04 | mA |  |
| $3 \mathrm{~V} / 5 \mathrm{~V}$ Operation |  |  | 0.01 | 0.06 | mA |  |
| Input Supply Current, 25 Mbps | IDDI (25) |  |  |  |  |  |
| $5 \mathrm{~V} / 3 \mathrm{~V}$ Operation |  |  | 2.2 | 3.5 | mA | 12.5 MHz logic signal frequency |
| $3 \mathrm{~V} / 5 \mathrm{~V}$ Operation |  |  | 2.0 | 2.8 | mA | 12.5 MHz logic signal frequency |
| Output Supply Current ${ }^{1}$, 25 Mbps | IDDo (25) |  |  |  |  |  |
| $5 \mathrm{~V} / 3 \mathrm{~V}$ Operation |  |  | 0.3 | 0.7 | mA | 12.5 MHz logic signal frequency |
| $3 \mathrm{~V} / 5 \mathrm{~V}$ Operation |  |  | 0.5 | 1.0 | mA | 12.5 MHz logic signal frequency |
| Input Supply Current, 50 Mbps | IDDI (50) |  |  |  |  |  |
| $5 \mathrm{~V} / 3 \mathrm{~V}$ Operation |  |  | 4.5 | 7.0 | mA | 25 MHz logic signal frequency |
| $3 \mathrm{~V} / 5 \mathrm{~V}$ Operation |  |  | 4.0 | 6.0 | mA | 25 MHz logic signal frequency |
| Output Supply Current ${ }^{1}$, 50 Mbps | IDDo (50) |  |  |  |  |  |
| $5 \mathrm{~V} / 3 \mathrm{~V}$ Operation |  |  | 1.2 | 1.6 | mA | 25 MHz logic signal frequency |
| $3 \mathrm{~V} / 5 \mathrm{~V}$ Operation |  |  | 1.0 | 1.5 | mA | 25 MHz logic signal frequency |
| Input Currents | $I_{\text {I }}$ | -10 | +0.01 | +10 | $\mu \mathrm{A}$ | $0 \mathrm{~V} \leq \mathrm{V}_{1 A}, \mathrm{~V}_{1 B}, \mathrm{~V}_{1 C}, \mathrm{~V}_{10} \leq \mathrm{V}_{\mathrm{DD} 1}$ or $\mathrm{V}_{\mathrm{DD} 2}$ |
| Logic High Output Voltage | V OH | $\mathrm{V}_{\mathrm{DD} 2}-0.1$ | 3.3 |  | V | $\mathrm{l}_{0}=-20 \mu \mathrm{~A}, \mathrm{~V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{IH}}$ |
| $5 \mathrm{~V} / 3 \mathrm{~V}$ Operation |  | $V_{D D 2}-0.5$ | 3.0 |  | V | $\mathrm{l}_{0}=-2.5 \mathrm{~mA}, \mathrm{~V}_{\mathrm{I}}=\mathrm{V}_{1 H}$ |
| Logic Low Output Voltage | Vol |  | 0.0 | 0.1 | V | $\mathrm{l}_{0}=20 \mu \mathrm{~A}, \mathrm{~V}_{\mathrm{l}}=\mathrm{V}_{\mathrm{IL}}$ |
| $5 \mathrm{~V} / 3 \mathrm{~V}$ Operation |  |  | 0.04 | 0.1 | V | $\mathrm{l}_{\mathrm{o}}=400 \mu \mathrm{~A}, \mathrm{~V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{IL}}$ |
|  |  |  | 0.3 | 0.4 | V | $\mathrm{l}_{0}=2.5 \mathrm{~mA}, \mathrm{~V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{IL}}$ |
| Logic High Output Voltage | Vor | $V_{\text {DD2 } 2}-0.1$ | 5.0 |  | V | $\mathrm{l}_{0}=-20 \mu \mathrm{~A}, \mathrm{~V}_{1}=\mathrm{V}_{\mathrm{VH}}$ |
| $3 \mathrm{~V} / 5 \mathrm{~V}$ Operation |  | $\mathrm{V}_{\mathrm{DD} 2}-0.8$ | 4.6 |  | V | $\mathrm{l}_{0}=-4 \mathrm{~mA}, \mathrm{~V}_{\mathrm{l}}=\mathrm{V}_{\mathrm{IH}}$ |
| Logic Low Output Voltage | Vol |  | 0.0 | 0.1 | V | $\mathrm{l}_{\mathrm{O}}=20 \mu \mathrm{~A}, \mathrm{~V}_{\mathrm{l}}=\mathrm{V}_{\mathrm{IL}}$ |
| $3 \mathrm{~V} / 5 \mathrm{~V}$ Operation |  |  | 0.03 | 0.1 | V | $\mathrm{l}_{0}=400 \mu \mathrm{~A}, \mathrm{~V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{IL}}$ |
|  |  |  |  | 0.8 |  | $\mathrm{lo}=4 \mathrm{~mA}, \mathrm{~V}_{\mathrm{l}}=\mathrm{V}_{\mathrm{IL}}$ |
| SWITCHING SPECIFICATIONS |  |  |  |  |  |  |
| For ADuM1100AR |  |  |  |  |  |  |
| Minimum Pulse Width ${ }^{2}$ | PW |  |  | 40 | ns | $C_{L}=15 \mathrm{pF}, \mathrm{CMOS}$ signal levels |
| Maximum Data Rate ${ }^{3}$ |  | 25 |  |  | Mbps | $C_{L}=15 \mathrm{pF}, \mathrm{CMOS}$ signal levels |
| For ADuM1100BR/ADuM1100UR |  |  |  |  |  |  |
| Minimum Pulse Width ${ }^{2}$ | PW |  |  | 20 | ns | $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}, \mathrm{CMOS}$ signal levels |
| Maximum Data Rate ${ }^{3}$ |  | 50 |  |  | Mbps | $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}, \mathrm{CMOS}$ signal levels |
| For All Grades |  |  |  |  |  |  |
| Propagation Delay Time to Logic Low/High Output ${ }^{4,5}$ | $\mathrm{t}_{\text {PHL, }} \mathrm{t}_{\text {PLH }}$ |  |  |  |  |  |
| $5 \mathrm{~V} / 3 \mathrm{~V}$ Operation (See Figure 9) |  |  | 13 | 21 | ns | $C_{L}=15 \mathrm{pF}, \mathrm{CMOS}$ signal levels |
| $3 \mathrm{~V} / 5 \mathrm{~V}$ Operation (See Figure 10) |  |  | 16 | 26 | ns | $C_{L}=15 \mathrm{pF}, \mathrm{CMOS}$ signal levels |

## ADuM1100

| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Pulse width Distortion, $\mid$ tPLH $-\left.t_{\text {PHL }}\right\|^{5}$ | PWD |  |  |  |  |  |
| $5 \mathrm{~V} / 3 \mathrm{~V}$ Operation |  |  | 0.5 | 2 | ns | $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$, CMOS signal levels |
| $3 \mathrm{~V} / 5 \mathrm{~V}$ Operation |  |  | 0.5 | 3 | ns | $C_{L}=15 \mathrm{pF}$, CMOS signal levels |
| Change in Pulse Width Distortion vs. Temperature ${ }^{6}$ |  |  |  |  |  |  |
| $5 \mathrm{~V} / 3 \mathrm{~V}$ Operation |  |  | 3 |  | $\mathrm{ps} /{ }^{\circ} \mathrm{C}$ | $C_{L}=15 \mathrm{pF}, \mathrm{CMOS}$ signal levels |
| $3 \mathrm{~V} / 5 \mathrm{~V}$ Operation |  |  | 10 |  | $\mathrm{ps} /{ }^{\circ} \mathrm{C}$ | $C_{L}=15 \mathrm{pF}, \mathrm{CMOS}$ signal levels |
| Propagation Delay Skew (Equal Temperature) ${ }^{5,7}$ | $\mathrm{tpSK1}$ |  |  |  |  |  |
| $5 \mathrm{~V} / 3 \mathrm{~V}$ Operation |  |  |  | 12 | ns | $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$, CMOS signal levels |
| $3 \mathrm{~V} / 5 \mathrm{~V}$ Operation |  |  |  | 15 | ns | $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$, CMOS signal levels |
| Propagation Delay Skew (Equal Temperature, Supplies) ${ }^{5,7}$ | tpSK2 |  |  |  |  |  |
| $5 \mathrm{~V} / 3 \mathrm{~V}$ Operation |  |  |  | 9 | ns | $C_{L}=15 \mathrm{pF}, \mathrm{CMOS}$ signal levels |
| $3 \mathrm{~V} / 5 \mathrm{~V}$ Operation |  |  |  | 12 | ns | $C_{L}=15 \mathrm{pF}$, CMOS signal levels |
| Output Rise/Fall Time (10\% to 90\%) | $\mathrm{t}_{\mathrm{R}}, \mathrm{t}_{\mathrm{F}}$ |  | 3 |  | ns | $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}, \mathrm{CMOS}$ signal levels |
| Common-Mode Transient Immunity at Logic Low/High Output ${ }^{8}$ | \|CMㄴ, |CM ${ }_{\mathbf{H}}$ \| | 25 | 35 |  | kV/ $\mu \mathrm{s}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{I}}=0 \mathrm{~V} \text { or } \mathrm{V}_{\mathrm{DD} 1}, \mathrm{~V}_{\mathrm{CM}}=1000 \mathrm{~V}, \\ & \text { transient magnitude }=800 \mathrm{~V} \end{aligned}$ |
| Refresh Rate | $\mathrm{fr}_{\mathrm{r}}$ |  |  |  |  |  |
| $5 \mathrm{~V} / 3 \mathrm{~V}$ Operation |  |  | 1.2 |  | Mbps |  |
| $3 \mathrm{~V} / 5 \mathrm{~V}$ Operation |  |  | 1.1 |  | Mbps |  |
| Input Dynamic Supply Current ${ }^{9}$ | CPD 1 |  |  |  |  |  |
| $5 \mathrm{~V} / 3 \mathrm{~V}$ Operation |  |  | 0.09 |  | mA/Mbps |  |
| $3 \mathrm{~V} / 5 \mathrm{~V}$ Operation |  |  | 0.08 |  | mA/Mbps |  |
| Output Dynamic Supply Current ${ }^{9}$ | $\mathrm{CPD2}$ |  |  |  |  |  |
| $5 \mathrm{~V} / 3 \mathrm{~V}$ Operation |  |  | 0.04 |  | mA/Mbps |  |
| $3 \mathrm{~V} / 5 \mathrm{~V}$ Operation |  |  | 0.02 |  | mA/Mbps |  |

${ }^{1}$ Output supply current values are with no output load present. See Figure 5 and Figure 6 for information on supply current variation with logic signal frequency. See the Power Consumption section for guidance on calculating the input and output supply currents for a given data rate and output load.
${ }^{2}$ The minimum pulse width is the shortest pulse width at which the specified pulse width distortion is guaranteed.
${ }^{3}$ The maximum data rate is the fastest data rate at which the specified pulse width distortion is guaranteed.
${ }^{4}$ tpHL is measured from the $50 \%$ level of the falling edge of the $V_{1}$ signal to the $50 \%$ level of the falling edge of the $V_{0}$ signal. tpLu is measured from the $50 \%$ level of the rising edge of the $V_{1}$ signal to the $50 \%$ level of the rising edge of the $V_{0}$ signal.
${ }^{5}$ Because the input thresholds of the ADuM1100 are at voltages other than the $50 \%$ level of typical input signals, the measured propagation delay and pulse width distortion can be affected by slow input rise/fall times. See the Propagation Delay-Related Parameters section and Figure 14 through Figure 18 for information on the impact of given input rise/fall times on these parameters.
${ }^{6}$ Pulse width distortion change vs. temperature is the absolute value of the change in pulse width distortion for a $1^{\circ} \mathrm{C}$ change in operating temperature.
${ }^{7} t_{\text {PKK }}$ is the magnitude of the worst-case difference in $t_{\text {PHL }}$ and/or $t_{\text {PLH }}$ that is measured between units at the same operating temperature and output load within the recommended operating conditions. $t_{\text {PSK } 2}$ is the magnitude of the worst-case difference in $t_{\text {PHL }}$ and/or $t_{\text {PLH }}$ that is measured between units at the same operating temperature, supply voltages, and output load within the recommended operating conditions.
${ }^{8} \mathrm{CM}_{H}$ is the maximum common-mode voltage slew rate that can be sustained while maintaining $\mathrm{V}_{\mathrm{O}}>0.8 \mathrm{~V}_{\mathrm{DD} 2}$. CML is the maximum common-mode voltage slew rate that can be sustained while maintaining $\mathrm{V}_{0}<0.8 \mathrm{~V}$. The common-mode voltage slew rates apply to both rising and falling edges. The transient magnitude is the range over which the common-mode is slewed.
${ }^{9}$ Dynamic supply current is the incremental amount of supply current required for a 1 Mbps increase in signal data rate. See Figure 5 and Figure 6 for information on supply current variation with logic signal frequency. See the Power Consumption section for guidance on calculating the input and output supply currents for a given data rate and output load.

## PACKAGE CHARACTERISTICS

Table 4.

| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Resistance (Input-to-Output) ${ }^{1}$ | Rto |  | $10^{12}$ |  | $\Omega$ |  |
| Capacitance (Input-to-Output) ${ }^{1}$ | Cloo |  | 1.0 |  | pF | $\mathrm{f}=1 \mathrm{MHz}$ |
| Input Capacitance ${ }^{2}$ | $\mathrm{Cl}_{1}$ |  | 4.0 |  | pF |  |
| IC Junction-to-Case Thermal Resistance, Side 1 | $\theta_{\text {Jcı }}$ |  | 46 |  | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ | Thermocouple located at |
| IC Junction-to-Case Thermal Resistance, Side 2 | $\theta_{\text {јсо }}$ |  | 41 |  | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ | center of package underside |
| Package Power Dissipation | PPD |  |  | 240 | mW |  |

${ }^{1}$ The device is considered a 2-terminal device; Pin 1, Pin 2, Pin 3, and Pin 4 are shorted together, and Pin 5, Pin 6, Pin 7, and Pin 8 are shorted together.
${ }^{2}$ Input capacitance is measured at Pin $2\left(\mathrm{~V}_{\mathrm{I}}\right)$.

## REGULATORY INFORMATION

The ADuM1100 is approved by the following organizations.
Table 5.

| UL | CSA | VDE |
| :--- | :--- | :--- |
| Recognized under 1577 | Approved under CSA Component | Certified according to DIN V VDE V |
| component recognition program ${ }^{1}$ | Acceptance Notice \#5A | $0884-10$ (VDE V 0884-10):2006-12 ${ }^{2}$ |
| Single/basic insulation, | Basic insulation per CSA 60950-1-03 and IEC 60950-1, | Reinforced insulation, 560 V peak |
| 2500 V rms isolation voltage | $400 \mathrm{~V} \mathrm{rms} \mathrm{(565} \mathrm{~V} \mathrm{peak)} \mathrm{maximum} \mathrm{working} \mathrm{voltage}$ |  |
| File E214100 | File 205078 | File 2471900-4880-0001 |

${ }^{1}$ In accordance with UL 1577 , each ADuM1100 is proof tested by applying an insulation test voltage $\geq 3000 \mathrm{Vrms}$ for 1 sec (current leakage detection limit $=5 \mu \mathrm{~A}$ ).
${ }^{2}$ In accordance with DIN V VDE V 0884-10, each ADuM1100 is proof tested by applying an insulation test voltage $\geq 1050 \mathrm{~V}$ peak for 1 sec (partial discharge detection limit $=5 \mathrm{pC}$ ). The * marking branded on the component designates DIN V VDE V 0884-10 approval.

## INSULATION AND SAFETY-RELATED SPECIFICATIONS

Table 6.

| Parameter | Symbol | Value | Unit | Conditions |
| :---: | :---: | :---: | :---: | :---: |
| Minimum External Air Gap (Clearance) | L(101) | 4.90 min | mm | Measured from input terminals to output terminals, shortest distance through air |
| Minimum External Tracking (Creepage) | L(102) | 4.01 min | mm | Measured from input terminals to output terminals, shortest distance path along body |
| Minimum Internal Gap (Internal Clearance) |  | 0.016 min | mm | Insulation distance through insulation |
| Tracking Resistance (Comparative Tracking Index) | CTI | >175 | V | DIN IEC 112/VDE 0303 Part 1 |
| Isolation Group |  | Illa |  | Material Group (DIN VDE 0110, 1/89, Table I) |
| Maximum Working Voltage Compatible with 50 Years Service Life | VIorm | 565 | $\checkmark$ peak | Continuous peak voltage across the isolation barrier |

## ADuM1100

## DIN V VDE V 0884-10 (VDE V 0884-10):2006-12 INSULATION CHARACTERISTICS

This isolator is suitable for reinforced isolation, only within the safety limit data. Maintenance of the safety data is ensured by means of protective circuits. The * marking on the package denotes DIN V VDE V 0884-10 approval for 560 V peak working voltage.

Table 7.

| Description | Conditions | Symbol | Characteristic | Unit |
| :---: | :---: | :---: | :---: | :---: |
| Installation Classification per DIN VDE 0110 |  |  |  |  |
| For Rated Mains Voltage $\leq 150 \mathrm{~V}$ rms |  |  | I to IV |  |
| For Rated Mains Voltage $\leq 300 \mathrm{~V}$ rms |  |  | I to III |  |
| For Rated Mains Voltage $\leq 400 \mathrm{~V}$ rms |  |  | I to II |  |
| Climatic Classification |  |  | 40/105/21 |  |
| Pollution Degree per DIN VDE 0110, Table 1 |  |  | 2 |  |
| Maximum Working Insulation Voltage |  | VIORM | 560 | $\checkmark$ peak |
| Input-to-Output Test Voltage, Method B1 | $\mathrm{V}_{\text {IORM }} \times 1.875=\mathrm{V}_{\mathrm{PR},} 100 \%$ production test, $\mathrm{t}_{\mathrm{m}}=1 \mathrm{sec}$, partial discharge $<5 \mathrm{pC}$ | $V_{\text {PR }}$ | 1050 | $\checkmark$ peak |
| Input-to-Output Test Voltage, Method A | $\begin{aligned} & \mathrm{V}_{\text {IORM }} \times 1.6=\mathrm{V}_{\text {PR, }}, \mathrm{t}_{\mathrm{m}}=60 \mathrm{sec} \text {, partial } \\ & \text { discharge }<5 \mathrm{pC} \end{aligned}$ | $V_{\text {PR }}$ |  |  |
| After Environmental Tests Subgroup 1 |  |  | 896 | $V$ peak |
| After Input and/or Safety Test Subgroup 2 and Subgroup 3 | $\mathrm{V}_{\text {IORM }} \times 1.2=\mathrm{V}_{\mathrm{PR},} \mathrm{t}_{\mathrm{m}}=60 \mathrm{sec}$, partial discharge $<5 \mathrm{pC}$ |  | 672 | $\checkmark$ peak |
| Highest Allowable Overvoltage | Transient overvoltage, $\mathrm{t}_{\text {TR }}=10$ seconds | $V_{\text {TR }}$ | 4000 | $V$ peak |
| Safety-Limiting Values | Maximum value allowed in the event of a failure (see Figure 2) |  |  |  |
| Case Temperature |  | Ts | 150 | ${ }^{\circ} \mathrm{C}$ |
| Side 1 Current |  | $\mathrm{I}_{\mathrm{S} 1}$ | 160 | mA |
| Side 2 Current |  | $\mathrm{I}_{5}$ | 170 | mA |
| Insulation Resistance at $\mathrm{T}_{\text {s }}$ | $\mathrm{V}_{10}=500 \mathrm{~V}$ | Rs | $>10^{9}$ | $\Omega$ |



Figure 2. Thermal Derating Curve, Dependence of Safety-Limiting Value with Case Temperature per DIN V VDE V 0884-10

## RECOMMENDED OPERATING CONDITIONS

Table 8.

| Parameter | Symbol | Min | Max | Unit |
| :---: | :---: | :---: | :---: | :---: |
| Operating Temperature |  |  |  |  |
| ADuM1100AR/ADuM1100BR | $\mathrm{T}_{\mathrm{A}}$ | -40 | +105 | ${ }^{\circ} \mathrm{C}$ |
| ADuM1100UR | $\mathrm{T}_{\text {A }}$ | -40 | +125 | ${ }^{\circ} \mathrm{C}$ |
| Supply Voltages ${ }^{1}$ | $V_{D D 1}$, $V_{D D 2}$ | 3.0 | 5.5 | V |
| Logic High Input Voltage, 5 V Operation ${ }^{1,2}$ <br> (See Figure 11 and Figure 12) | $\mathrm{V}_{\text {IH }}$ | 2.0 | $\mathrm{V}_{\mathrm{DD} 1}$ | V |
| Logic Low Input Voltage, <br> 5 V Operation ${ }^{1,2}$ <br> (See Figure 11 and Figure 12) | $\mathrm{V}_{\text {IL }}$ | 0.0 | 0.8 | V |
| Logic High Input Voltage, <br> 3.3V Operation ${ }^{1,2}$ <br> (See Figure 11 and Figure 12) | $\mathrm{V}_{\text {IH }}$ | 1.5 | $\mathrm{V}_{\mathrm{DD} 1}$ | V |
| Logic Low Input Voltage, 3.3 V Operation ${ }^{1,2}$ (See Figure 11 and Figure 12) | VIL | 0.0 | 0.5 | V |
| Input Signal Rise and Fall Times |  |  | 1.0 | ms |

[^1]
## ABSOLUTE MAXIMUM RATINGS

Table 9.

| Parameter | Symbol | Min | Max | Unit |
| :---: | :---: | :---: | :---: | :---: |
| Storage Temperature | $\mathrm{T}_{\text {st }}$ | -55 | +150 | ${ }^{\circ} \mathrm{C}$ |
| Ambient Operating Temperature | $\mathrm{T}_{\text {A }}$ | -40 | +125 | ${ }^{\circ} \mathrm{C}$ |
| Supply Voltages ${ }^{1}$ | $\mathrm{V}_{\mathrm{DD1}}, \mathrm{~V}_{\mathrm{DD} 2}$ | -0.5 | +6.5 | V |
| Input Voltage ${ }^{1}$ | $V_{1}$ | -0.5 | $\mathrm{V}_{\mathrm{DDI} 1}+0.5$ | V |
| Output Voltage ${ }^{1}$ | Vo | -0.5 | $\mathrm{V}_{\mathrm{DO} 2}+0.5$ | V |
| Average Current, per Pin ${ }^{2}$ |  |  |  | mA |
| Temperature $\leq 105^{\circ} \mathrm{C}$ |  |  | +25 | mA |
| Input Current |  | -7 | +7 | mA |
| Output Current |  | -20 | +20 | mA |
| Common-Mode Transients ${ }^{3}$ |  | -100 | +100 | kV/ $/ \mathrm{s}$ |

${ }^{1}$ All voltages are relative to their respective ground.
${ }^{2}$ See Figure 2 for information on maximum allowable current for various temperatures.
${ }^{3}$ Refers to common-mode transients across the insulation barrier. Common-mode transients exceeding the Absolute Maximum Rating may cause latch-up or permanent damage.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

Table 10. Truth Table (Positive Logic)

| $\mathbf{V}_{\mathbf{I}}$ Input | V $_{\text {DD } 1}$ State | V $_{\text {DD } 2 \text { State }}$ | V $_{0}$ Output |
| :--- | :--- | :--- | :--- |
| H | Powered | Powered | H |
| L | Powered | Powered | L |
| X | Unpowered | Powered | $\mathrm{H}^{1}$ |
| X | Powered | Unpowered | $\mathrm{X}^{1}$ |

${ }^{1}$ VO returns to VI state within $1 \mu \mathrm{~s}$ of power restoration.

Figure 3 shows the package branding. * is the DIN EN 60747-5-2 mark, R is the package designator ( R denotes SOIC_N), YYWW is the date code, and XXXXXX is the lot code.


Figure 3. Package Branding

## ADuM1100

## PIN CONFIGURATION AND FUNCTION DESCRIPTIONS


${ }^{1}$ PIN 1 AND PIN 3 ARE INTERNALLY CONNECTED. EITHER OR BOTH MAY BE USED FOR VD1.
${ }^{2}$ PIN 5 AND PIN 7 ARE INTERNALLY CONNECTED. EITHER OR BOTH MAY BE USED FOR GND ${ }_{2}$

Figure 4. Pin Configuration
Table 11. Pin Function Descriptions

| Pin No. | Mnemonic | Description |
| :--- | :--- | :--- |
| 1 | $\mathrm{~V}_{\mathrm{DD} 1}$ | Input Supply Voltage, 3.0 V to 5.5 V. |
| 2 | $\mathrm{~V}_{1}$ | Logic Input. |
| 3 | $\mathrm{~V}_{\mathrm{DD} 1}$ | Input Supply Voltage, 3.0 V to 5.5 V. |
| 4 | $\mathrm{GND}_{1}$ | Input Ground Reference. |
| 5 | $\mathrm{GND}_{2}$ | Output Ground Reference. |
| 6 | $\mathrm{~V}_{\mathrm{o}}$ | Logic Output. |
| 7 | $\mathrm{GND}_{2}$ | Output Ground Reference. |
| 8 | $\mathrm{~V}_{\mathrm{DD} 2}$ | Output Supply Voltage, 3.0 V to 5.5 V. |

## TYPICAL PERFORMANCE CHARACTERISTICS



Figure 5. Typical Input Supply Current vs. Logic Signal Frequency for 5 V and 3.3 V Operation


Figure 6. Typical Output Supply Current vs. Logic Signal Frequency for 5 V and 3.3 V Operation


Figure 7. Typical Propagation Delays vs. Temperature, 5 V Operation


Figure 8. Typical Propagation Delays vs. Temperature, 3.3 V Operation


Figure 9. Typical Propagation Delays vs. Temperature, 5 V/3 V Operation


Figure 10. Typical Propagation Delays vs. Temperature, 3 V/5 V Operation

## ADuM1100



Figure 11. Typical Input Voltage Switching Threshold, Low-to-High Transition


Figure 12. Typical Input Voltage Switching Threshold, High-to-Low Transition

## APPLICATION INFORMATION

## PC BOARD LAYOUT

The ADuM1 100 digital isolator requires no external interface circuitry for the logic interfaces. A bypass capacitor is recommended at the input and output supply pins. The input bypass capacitor can conveniently be connected between Pin 3 and Pin 4 (see Figure 13). Alternatively, the bypass capacitor can be located between Pin 1 and Pin 4. The output bypass capacitor can be connected between Pin 7 and Pin 8 or Pin 5 and Pin 8 . The capacitor value should be between $0.01 \mu \mathrm{~F}$ and $0.1 \mu \mathrm{~F}$. The total lead length between both ends of the capacitor and the power supply pins should not exceed 20 mm .


Figure 13. Recommended Printed Circuit Board Layout

## PROPAGATION DELAY-RELATED PARAMETERS

Propagation delay time describes the length of time it takes for a logic signal to propagate through a component. Propagation delay time to logic low output and propagation delay time to logic high output refer to the duration between an input signal transition and the respective output signal transition (see Figure 14).


Figure 14. Propagation Delay Parameters

Pulse width distortion is the maximum difference between $t_{\text {PLH }}$ and tphe and provides an indication of how accurately the input signal's timing is preserved in the component's output signal. Propagation delay skew is the difference between the minimum and maximum propagation delay values among multiple ADuM1100 components operated at the same operating temperature and having the same output load.
Depending on the input signal rise/fall time, the measured propagation delay based on the input $50 \%$ level can vary from the true propagation delay of the component (as measured from its input switching threshold). This is because the input threshold, as is the case with commonly used optocouplers, is at a different voltage level than the $50 \%$ point of typical input signals. This propagation delay difference is given by

$$
\begin{aligned}
& \Delta_{L H}=t_{P L H}^{\prime}-t_{P L H}=\left(t_{R} / 0.8 V_{I}\right)\left(0.5 V_{I}-V_{I T H(L-H)}\right) \\
& \Delta_{H L}=t_{P H L}^{\prime}-t_{P H L}=\left(t_{F} / 0.8 V_{I}\right)\left(0.5 V_{I}-V_{I T H(H-L)}\right)
\end{aligned}
$$

where:
$t_{P L H}$ and $t_{P H L}$ are the propagation delays as measured from the input $50 \%$ level.
$t_{P L H}^{\prime}$ and $t^{\prime}{ }_{P H L}$ are the propagation delays as measured from the input switching thresholds.
$t_{R}$ and $t_{F}$ are the input $10 \%$ to $90 \%$ rise/fall times.
$V_{I}$ is the amplitude of the input signal ( 0 to $V_{I}$ levels assumed). $V_{I T H(L-H}$ and, $V_{I T H(H-L)}$ are the input switching thresholds.


Figure 15. Impact of Input Rise/Fall Time on Propagation Delay

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Figure 16. Typical Propagation Delay Change due to Input Rise Time Variation (for $V_{D D 1}=3.3 \mathrm{~V}$ and 5 V )


Figure 17. Typical Propagation Delay Change due to Input Fall Time Variation (for $V_{D D I}=3.3 \mathrm{~V}$ and 5 V )

The impact of the slower input edge rates can also affect the measured pulse width distortion as based on the input $50 \%$ level. This impact can either increase or decrease the apparent pulse width distortion depending on the relative magnitudes of $t_{\text {PHL }}, t_{\text {PLH }}$, and PWD. The case of interest here is the condition that leads to the largest increase in pulse width distortion. The change in this case is given by

$$
\begin{aligned}
& \Delta_{\mathrm{PWD}}=P W D^{\prime}-P W D=\Delta_{L H}-\Delta_{H L}= \\
& \left(t / 0.8 V_{I}\right)\left(V-V_{I T H(L-H)}-V_{I T H(H-L)}\right),\left(\text { for } t=t_{r}=t_{f}\right)
\end{aligned}
$$

where:
$P W D=\left|t_{P L H}-t_{P H L}\right|$
$P W D^{\prime}=\left|t_{P L H}^{\prime}-t_{P H L}^{\prime}\right|$.
This adjustment in pulse width distortion is plotted as a function of input rise/fall time in Figure 18.


Figure 18. Typical Pulse Width Distortion Adjustment due to Input Rise/Fall Time Variation (at VDD1 $=3.3 \mathrm{~V}$ and 5 V )

## METHOD OF OPERATION, DC CORRECTNESS, AND MAGNETIC FIELD IMMUNITY

The two coils in Figure 1 act as a pulse transformer. Positive and negative logic transitions at the isolator input cause narrow ( 2 ns ) pulses to be sent via the transformer to the decoder. The decoder is bistable and therefore either set or reset by the pulses indicating input logic transitions. In the absence of logic transitions at the input for more than $\sim 1 \mu \mathrm{~s}$, a periodic update pulse of the appropriate polarity is sent to ensure dc correctness at the output. If the decoder receives none of these update pulses for more than about $5 \mu \mathrm{~s}$, the input side is assumed to be unpowered or nonfunctional, in which case the isolator output is forced to a logic high state by the watchdog timer circuit.
The limitation on the magnetic field immunity of the ADuM1100 is set by the condition in which induced voltage in the transformer's receiving coil is sufficiently large to either falsely set or reset the decoder. The analysis that follows defines the conditions under which this can occur. The 3.3 V operating condition of the ADuM1100 is examined because it represents the most susceptible mode of operation.
The pulses at the transformer output are greater than 1.0 V in amplitude. The decoder has sensing thresholds at about 0.5 V , therefore establishing a 0.5 V margin in which induced voltages can be tolerated. The induced voltage induced across the receiving coil is given by

$$
V=(-\mathrm{d} \beta / d t) \sum \pi r_{n}^{2}, n=1,2, \ldots, N
$$

where:
$\beta$ is the magnetic flux density (gauss).
$N$ is the number of turns in receiving coil.
$r_{n}$ is the radius of $n$th turn in receiving coil (cm).

Given the geometry of the receiving coil in the ADuM1100 and an imposed requirement that the induced voltage be at most $50 \%$ of the 0.5 V margin at the decoder, a maximum allowable magnetic field is calculated, as shown in Figure 19.


Figure 19. Maximum Allowable External Magnetic Field
For example, at a magnetic field frequency of 1 MHz , the maximum allowable magnetic field of 0.2 kgauss induces a voltage of 0.25 V at the receiving coil. This is about $50 \%$ of the sensing threshold and does not cause a faulty output transition. Similarly, if such an event were to occur during a transmitted pulse (and was of the worst-case polarity), it would reduce the received pulse from $>1.0 \mathrm{~V}$ to 0.75 V , still well above the 0.5 V sensing threshold of the decoder.

The preceding magnetic flux density values correspond to specific current magnitudes at given distances away from the ADuM1100 transformers. Figure 20 expresses these allowable current magnitudes as a function of frequency for selected distances. As can be seen, the ADuM1100 is extremely immune and can be affected only by extremely large currents operated at high frequency and very close to the component. For the 1 MHz example noted, one would have to place a current of 0.5 kA 5 mm away from the ADuM1100 to affect the component's operation.


Figure 20. Maximum Allowable Current for Various Current-to-ADuM1100 Spacings

Note that at combinations of strong magnetic field and high frequency, any loops formed by printed circuit board traces could induce sufficiently large error voltages to trigger the thresholds of succeeding circuitry. Care should be taken in the layout of such traces to avoid this possibility.

## POWER CONSUMPTION

The supply current of the ADuM1100 isolator is a function of the supply voltage, the input data rate, and the output load.
The input supply current is given by

$$
\begin{array}{ll}
I_{D D I}=I_{D D I(Q)} & f \leq 0.5 f_{r} \\
I_{D D I}=I_{D D I(D)} \times\left(2 f-f_{r}\right)+I_{D D I}(Q) & f>0.5 f_{r}
\end{array}
$$

The output supply current is given by

$$
\begin{array}{rr}
I_{D D O}=I_{D D O(Q)} & f \leq 0.5 f_{r} \\
I_{D D O}=\left(I_{D D O(D)}+\left(0.5 \times 10^{-3}\right) \times C_{L} V_{D D O}\right) \times\left(2 f-f_{r}\right)+I_{D D O(Q)} \\
& f>0.5 f_{r}
\end{array}
$$

where:
$I_{D D I(D)}, I_{D D O(D)}$ are the input and output dynamic supply currents per channel (mA/Mbps).
$C_{L}$ is output load capacitance ( pF ).
$V_{D D O}$ is the output supply voltage $(\mathrm{V})$.
$f$ is the input logic signal frequency ( MHz , half of the input data rate, NRZ signaling).
$f_{r}$ is the input stage refresh rate (Mbps).
$I_{D D I(Q)}, I_{D D O(Q)}$ are the specified input and output quiescent supply currents (mA).

## ADuM1100

## OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MS-012-AA
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 21. 8-Lead Standard Small Outline Package [SOIC_N] Narrow Body (R-8)
Dimensions shown in millimeters and (inches)

## ORDERING GUIDE

| Model | Temperature Range | Maximum Data Rate (Mbps) | Minimum Pulse Width (ns) | Package Description | Package Option |
| :---: | :---: | :---: | :---: | :---: | :---: |
| ADuM1100AR | $-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ | 25 | 40 | 8-Lead SOIC_N | R-8 |
| ADuM1100AR-RL7 | $-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ | 25 | 40 | 8-Lead SOIC_N, 1,000 Piece Reel | R-8 |
| ADuM1100ARZ ${ }^{1}$ | $-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ | 25 | 40 | 8-Lead SOIC_N | R-8 |
| ADuM1100ARZ-RL7 ${ }^{1}$ | $-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ | 25 | 40 | 8-Lead SOIC_N, 1,000 Piece Reel | R-8 |
| ADuM1100BR | $-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ | 100 | 10 | 8-Lead SOIC_N | R-8 |
| ADuM1100BR-RL7 | $-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ | 100 | 10 | 8-Lead SOIC_N, 1,000 Piece Reel | R-8 |
| ADuM1100BRZ ${ }^{1}$ | $-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ | 100 | 10 | 8-Lead SOIC_N | R-8 |
| ADuM1100BRZ-RL7 ${ }^{1}$ | $-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ | 100 | 10 | 8-Lead SOIC_N, 1,000 Piece Reel | R-8 |
| ADuM1100UR | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 100 | 10 | 8-Lead SOIC_N | R-8 |
| ADuM1100UR-RL7 | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 100 | 10 | 8-Lead SOIC_N, 1,000 Piece Reel | R-8 |
| ADuM1100URZ ${ }^{1}$ | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 100 | 10 | 8-Lead SOIC_N | R-8 |
| ADuM1100URZ-RL71 ADuM1100EVAL | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 100 | 10 | 8-Lead SOIC_N, 1,000 Piece Reel Evaluation Board | R-8 |

${ }^{1} Z=$ RoHS Compliant Part.
ADuM1 100

NOTES

## ADuM1100

## NOTES


[^0]:    ${ }^{1}$ Protected by U.S. Patents 5,952,849; 6,525,566; 6,922,080; 6,903,578; 6,873,065; 7,075,329; and other pending patents.

[^1]:    ${ }^{1}$ All voltages are relative to their respective ground.
    ${ }^{2}$ Input switching thresholds have 300 mV of hysteresis. See the Method of Operation, DC Correctness, and Magnetic Field Immunity section, Figure 19, and Figure 20 for information on immunity to external magnetic fields.

